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Smallest aspect-ratio form-birefringence half-wave plate

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Form-birefringence elements

Subwavelength 0th order gratings permit to create a phase-shift between the polarized 0th order grating modes propagating down the slits and grooves of a binary corrugation, and to transform the polarization of an incident beam. The phase-shift per unit height of the grating is an increasing function of the refractive index difference between ridges and grooves. If the ridges are made by photolithography in a resist or by polymer embossing, the low refractive index leads to a very large corrugation aspect ratio (approx. 4 for a half-wave phase-shift) that is difficult to fabricate and/or provides insufficient mechanical stability. If the ridges are made in a high index non-organic material (e.g. a semiconductor) the needed depth is reduced (although still notably larger than 1 for a half-wave phase-shift). However, another problem is now encountered: due to a more significant Fabry-Perot effect between the upper and lower boundaries of the 0th order grating [1] high transmission is guaranteed only if its resonance condition is ensured for both polarizations simultaneously. The three conditions (π phase-shift between TE and TM and both Fabry-Perot resonances) are impossible to achieve simultaneously if the corrugation is made by directly etching the substrate (same material for ridges and substrate) unless the grooves are very deep which imposes difficult etching conditions [2]. Using an inventive design by phase management of the involved grating modes [2] we have found that all three conditions can indeed be satisfied in a binary grating of reasonable aspect ratio (still larger than 1) when the substrate has a refractive index notably smaller than the ridges.

Smallest aspect-ratio half-wave plate

The obtained electromagnetic condition is wavelength dependent; thus a choice was made for a Yb:YAG laser in the objective of defining a spatially resolved polarization rotating element for this type of laser, creating radially polarized light. Figure 1 sketches the structure to be fabricated. The substrate is fused quartz, having a grating on top made of well known solar cell PECVD amorphous silicon [3] (a-Si) of 244 nm thickness.

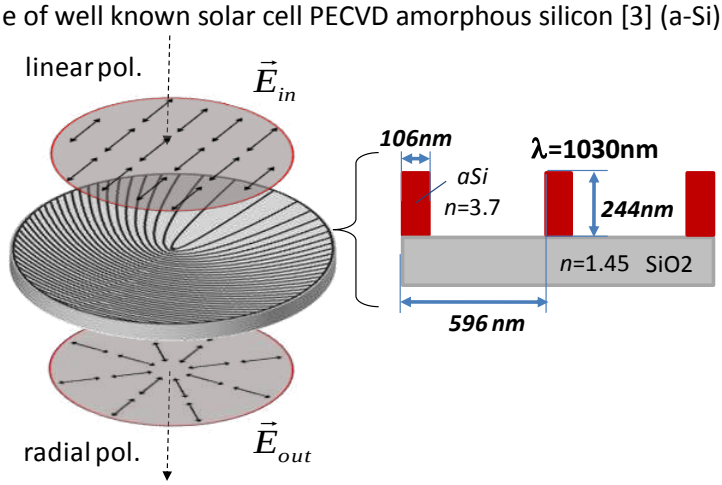

Fig. 1 Aspect-ratio minimized a-Si half-wave 0th order grating for creating radial polarization

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The photolithography of the 596 nm period grating was made by hard-contact chromium mask transfer followed by wet-chemical thinning of the photoresist ridges so as to end up with ridges of about 100 nm width. A reactive ion etching process was then applied to transfer the resist profile into the amorphous silicon layer down to the quartz surface. Figure 2 shows SEM images of a cleaved a-Si grating. The optical function of the element was assessed experimentally exhibiting locally a transmission larger than 97% for both polarizations and an optical phase-shift between polarizations of close to the desired 180 degrees. Preliminary laser flux resistance tests were made with a femtosecond Yb:YAG laser beam showing that the damage threshold of the fabricated element is close to the machining operation conditions of this laser [4], leading to the conclusion that a more reliable microstructuring technology will give a sufficient security margin for an operation without requiring beam diameter expansion.

Toward a reliable manufacturing technology

The needed aspect ratio limited structure can ideally be manufactured by means of high-end microelectronic technology starting with the writing of a chromium reticle followed by the 4x reduction factor step and repeat projection by means of a 248 nm stepper onto a 200 mm diameter borofloat glass wafer with a 250 nm TEOS oxide hard mask on top. The photolithography of the 613 nm period grating was made by KrF stepper lithography. Before proceeding to the ICP etch, a controlled trimming of the resist ridges is still needed to obtain the specified duty cycle and aspect-ratio with an ideally 113nm wide ridge basis.

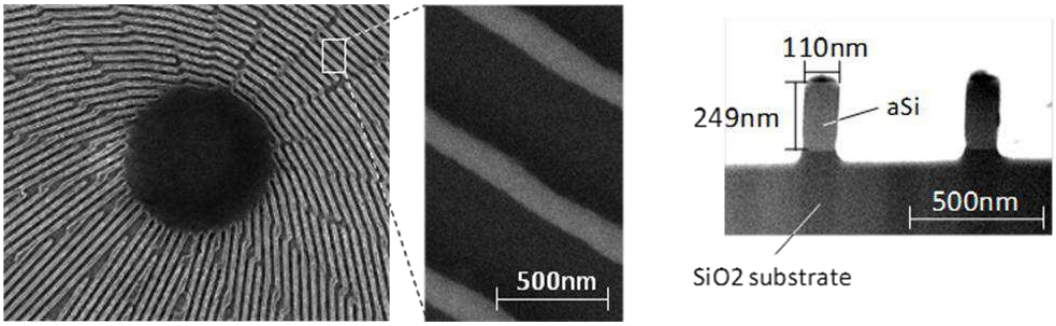

Fig. 2. SEM image of the central region (left) and of a cross-section (FIB-slice) of the half-wave laboratory prototype for creating radial polarization

Beyond the achievement of this particular polarization-rotating element, the present undertaking aims at concretely evaluating what microelectronic technology can do for the batch manufacturing of wavelength-scale diffractive elements for the processing of free space waves. The presentation will report on the technological problems, the structure uniformity at the wafer level and the yield. A manufacturing cost estimate will also be made.

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